

2MBI150VB-120-50

IGBT Modules

IGBT MODULE (V series) 1200V / 150A / 2 in one package

Features

High speed switching Voltage drive Low Inductance module structure

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as Welding machines

Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T₀=25°C unless otherwise specified)

Items	Symbols	Conditions	Conditions		Units	
Collector-Emitter voltage	VCES			1200	V	
Gate-Emitter voltage	Vges			±20	V	
Collector current	lc	Continuous	Tc=100°C	150		
	C pulse	1ms		300		
	-lc			150		
	- C pulse	1ms	1ms			
Collector power dissipation	Pc	1 device		1070	W	
Junction temperature	Tj			175		
Operating junction temperature (under switching conditions)	Tjop				°C	
Case temperature	Tc				C	
Storage temperature	Tstg					
Isolation voltage between terminal and copper base (*1)	Viso	AC : 1min.		2500	VAC	
Screw torque Mounting (*2)	-			3.5	Nm	
Terminals (*3)	-			3.5		

Note *1: All terminals should be connected together during the test.

Note *2: Recommendable Value : 2.5-3.5 Nm (M5 or M6) Note *3: Recommendable Value : 2.5-3.5 Nm (M5)

• Electrical characteristics (at T_j= 25°C unless otherwise specified)

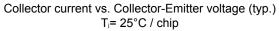
li anno	Symbole	Symbols Conditions		Characteristics		ics	Linita
Items	Symbols			min.	typ.	max.	Units
Zero gate voltage collector current	ICES	V _{GE} = 0V, V _{CE} = 1200V		-	-	2.0	mA
Gate-Emitter leakage current	Iges	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	400	nA
Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 150mA		6.0	6.5	7.0	V
Collector-Emitter saturation voltage	V	V _{GE} = 15V I _c = 150A	Tj=25°C	-	2.00	2.45	V
	V _{CE (sat)} (terminal)		Tj=125°C	-	2.35	-	
	(terminal)		Tj=150°C		2.40		
	V _{CE (sat)}	V _{GE} = 15V I _c = 150A	Tj=25°C	-	1.85	2.30	
	(chip)		Tj=125°C	-	2.20	-	
	(criip)		Tj=150°C		2.25		
Internal gate resistance	R _G (int)	-		-	5.0	-	Ω
Input capacitance	Cies	$V_{CE} = 10V, V_{GE} = 0V, f = 1MHz$		-	12.0	-	nF
Turn-on time	ton	V _{cc} = 600V L _s = 30nH I _c = 150A V _{GE} = ±15V		-	600	-	nsec
	tr			-	200	-	
	tr (i)			-	50	-	
Turn-off time	toff	$R_G = 4.2\Omega$		-	800	-	
	tr	T _j = 150°C		-	80	-]
Forward on voltage	VF	$V_{GF} = 0V$	Tj=25°C	-	1.85	2.30	
	(terminal)	$V_{GE} = 0V$ $I_F = 150A$	Tj=125°C	-	2.00	-	V
	(terminar)	I⊧ = 150A	Tj=150°C		1.95		
	VF	$\gamma = 0\gamma$	Tj=25°C	-	1.70	2.15	
		V _{GE} = 0V I _F = 150A	Tj=125°C	-	1.85	-	
	(chip)		Tj=150°C		1.80		
Reverse recovery time	trr	I⊧ = 150A		-	150	-	nsec

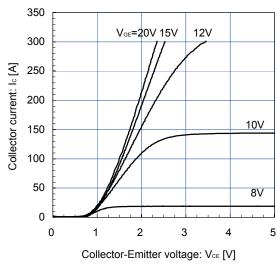
• Thermal resistance characteristics

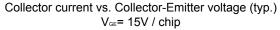
Items	Symbols	Conditions	Characteristics			Units
		Conditions	min.	typ.	max.	Units
Thermal resistance (1device)	Rth(j-c)	IGBT	-	-	0.140	°C/W
		FWD	-	-	0.200	
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.025	-	

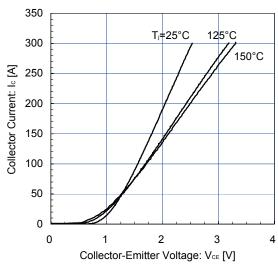
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

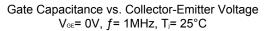
Characteristics (Representative)

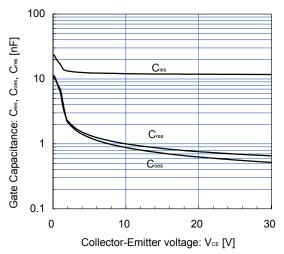


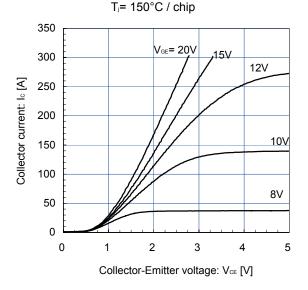






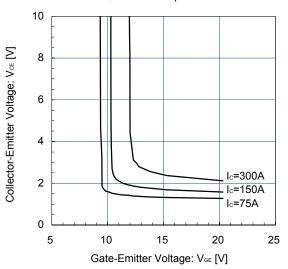




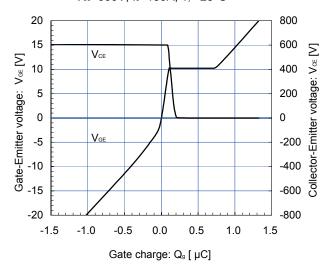


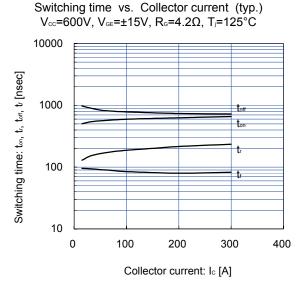
Collector current vs. Collector-Emitter voltage (typ.)

Collector-Emitter voltage vs. Gate-Emitter voltage T_i = 25°C / chip

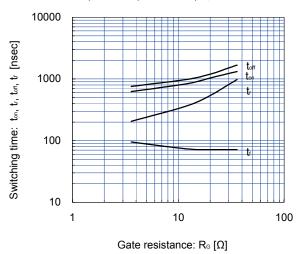


Dynamic Gate Charge (typ.) Vcc=600V, Ic=150A, Tj= 25°C

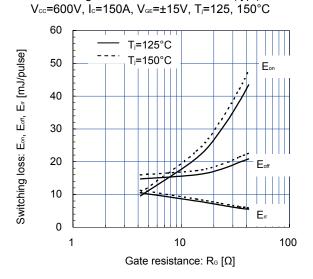


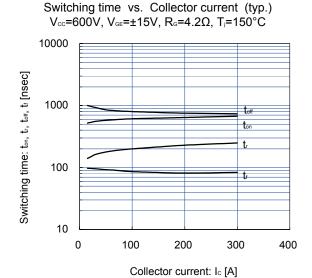


Switching time vs. Gate resistance (typ.) V_{cc} =600V, Ic=150A, V_{GE} =±15V, Tj=125°C

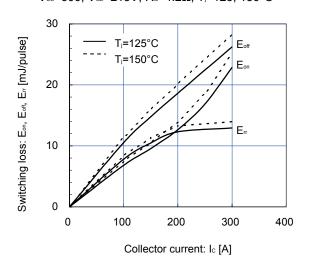


Switching loss vs. Gate resistance (typ.)

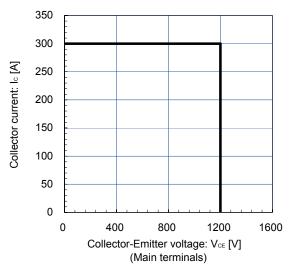




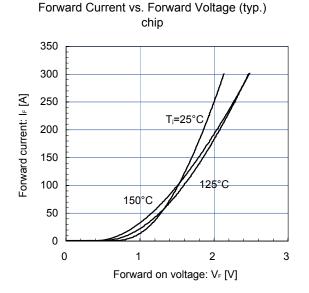
Switching loss vs. Collector current (typ.) V_{cc} =600, V_{ce} =±15V, R_{c} =4.2 Ω , T_{j} =125, 150°C



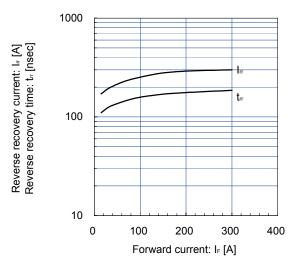
Reverse bias safe operating area (max.) $+V_{GE}=15V$, $-V_{GE}=15V$, $R_{G}=4.2\Omega$, $T_{J}=150^{\circ}C$

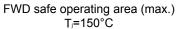


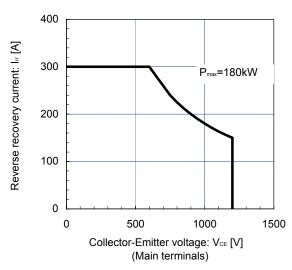
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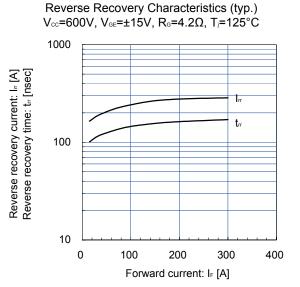


Reverse Recovery Characteristics (typ.) V_{cc} =600V, V_{ce} =±15V, R_{c} =4.2 Ω , T_j=150°C

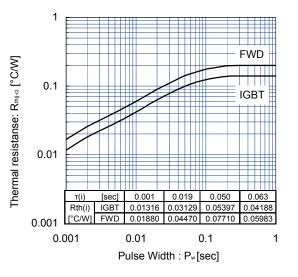






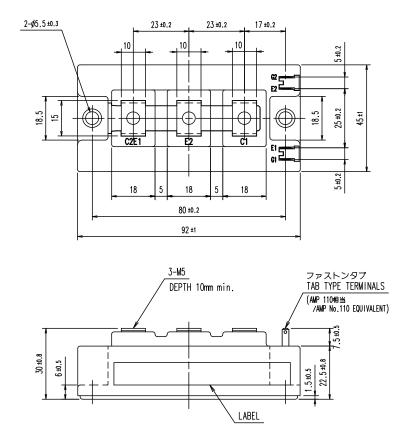


Transient Thermal Resistance (max.)

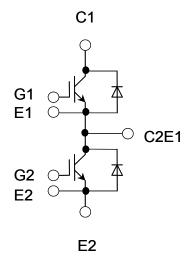


http://www.fujielectric.com/products/semiconductor/

Outline Drawings, mm



Equivalent Circuit Schematic



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